MJE243 - NPN, MJE253 - PNP

Preferred Device

Complementary Silicon Power Plastic Transistors

These devices are designed for low power audio amplifier and low-current, high-speed switching applications.

Features

• High Collector-Emitter Sustaining Voltage -

 $V_{CEO(sus)} = 100 \text{ Vdc (Min)}$

• High DC Current Gain @ I_C = 200 mAdc

 $h_{FE} = 40 - 200$

=40-120

• Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 0.3 \text{ Vdc (Max)} @ I_C = 500 \text{ mAdc}$

• High Current Gain Bandwidth Product -

 $f_T = 40 \text{ MHz (Min)} @ I_C = 100 \text{ mAdc}$

• Annular Construction for Low Leakages

 I_{CBO} = 100 nAdc (Max) @ Rated V_{CB}

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	100	Vdc
Collector-Base Voltage	V _{CB}	100	Vdc
Emitter-Base Voltage	V _{EB}	7.0	Vdc
Collector Current - Continuous - Peak	I _C	4.0 8.0	Adc
Base Current	I _B	10	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	15 120	W mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{\sf JC}$	8.34	°C/W
Thermal Resistance, Junction-to-Ambient	θ_{JA}	83.4	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



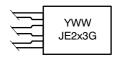
ON Semiconductor®

http://onsemi.com

4.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 100 VOLTS, 15 WATTS



MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping
MJE243	TO-225	500 Units/Box
MJE243G	TO-225 (Pb-Free)	500 Units/Box
MJE253	TO-225	500 Units/Box
MJE253G	TO-225 (Pb-Free)	500 Units/Box

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	-		•	
Collector-Emitter Sustaining Voltage ($I_C = 10 \text{ mAdc}, I_B = 0$)	V _{CEO(sus)}	100	_	Vdc
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CE} = 100 \text{ Vdc}, I_E = 0, T_C = 125^{\circ}\text{C})$	I _{CBO}		0.1 0.1	μAdc
Emitter Cutoff Current ($V_{BE} = 7.0 \text{ Vdc}$, $I_{C} = 0$)	I _{EBO}	-	0.1	μAdc
ON CHARACTERISTICS	<u>.</u>	•		
DC Current Gain ($I_C = 200 \text{ mAdc}$, $V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 1.0 \text{ Adc}$, $V_{CE} = 1.0 \text{ Vdc}$)	h _{FE}	40 15	180	-
Collector-Emitter Saturation Voltage ($I_C = 500 \text{ mAdc}$, $I_B = 50 \text{ mAdc}$) ($I_C = 1.0 \text{ Adc}$, $I_B = 100 \text{ mAdc}$)	V _{CE(sat)}	- -	0.3 0.6	Vdc
Base-Emitter Saturation Voltage (I _C = 2.0 Adc, I _B = 200 mAdc)	V _{BE(sat)}	-	1.8	Vdc
Base-Emitter On Voltage (I _C = 500 mAdc, V _{CE} = 1.0 Vdc)	V _{BE(on)}	-	1.5	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain - Bandwidth Product (I _C = 100 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz)	f⊤	40	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	-	50	pF

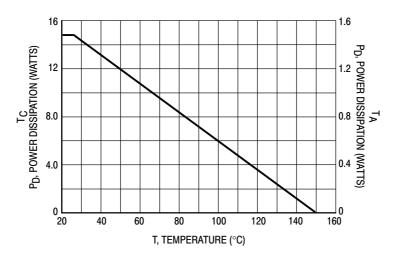


Figure 1. Power Derating

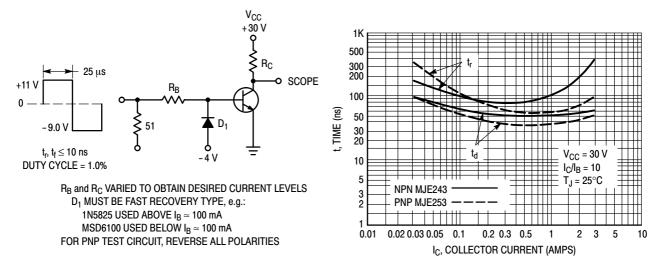


Figure 2. Switching Time Test Circuit

Figure 3. Turn-On Time

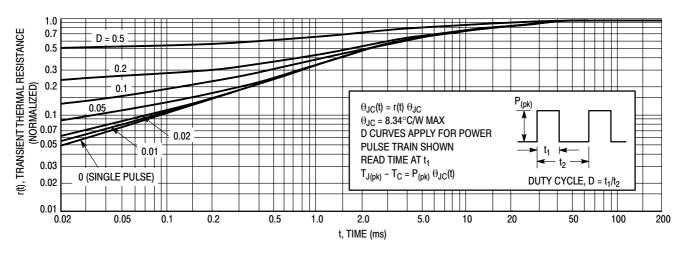


Figure 4. Thermal Response

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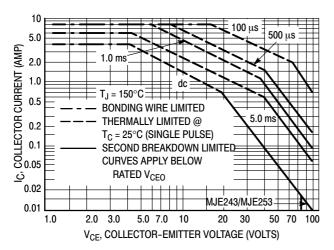


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

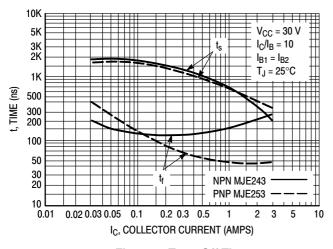


Figure 6. Turn-Off Time

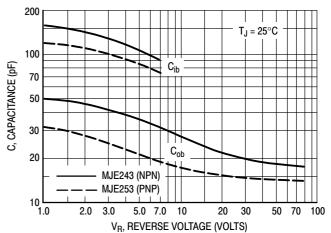


Figure 7. Capacitance

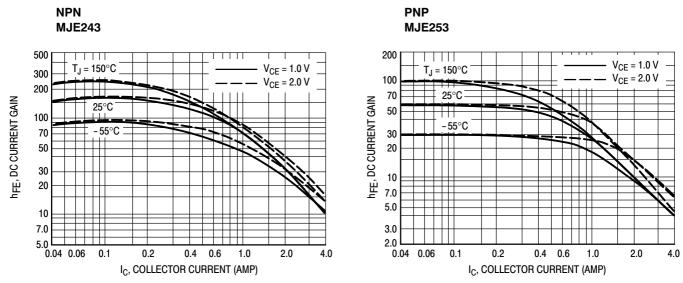


Figure 8. DC Current Gain

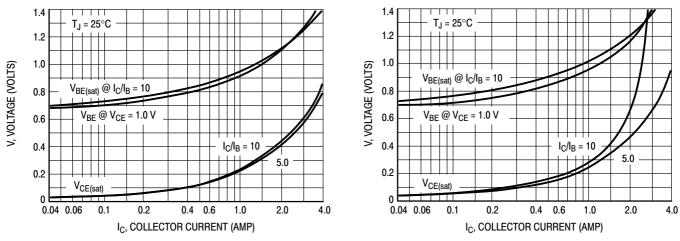


Figure 9. "On" Voltages

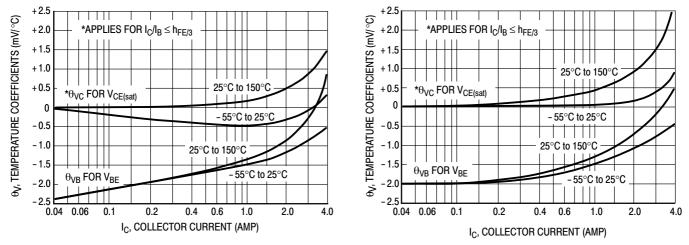
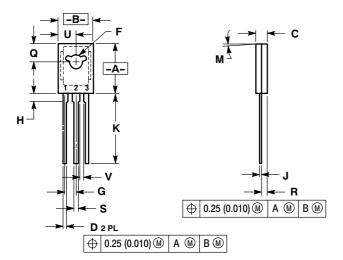


Figure 10. Temperature Coefficients

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PACKAGE DIMENSIONS

TO-225 CASE 77-09 **ISSUE Z**



NOTES:

- 11. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.425	0.435	10.80	11.04
В	0.295	0.305	7.50	7.74
С	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094	BSC	2.39	BSC
Н	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040		1.02	

STYLE 1:

EMITTER PIN 1. 2. COLLECTOR BASE

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